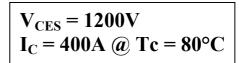
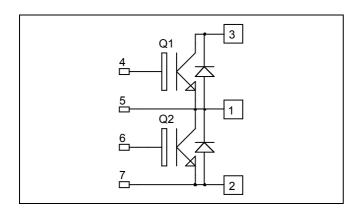


Phase leg Trench + Field Stop IGBT3 Power Module





#### **Application**

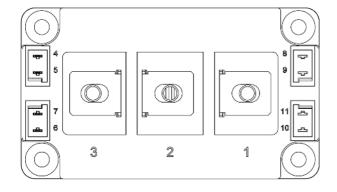
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors



- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T<sub>C</sub> of V<sub>CEsat</sub>
- RoHS Compliant



#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1200	V
Ţ	Continuous Collector Current	$T_C = 25$ °C	580	
$I_{\rm C}$	Continuous Conector Current	$T_C = 80$ °C	400	Α
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	800	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_D$	Maximum Power Dissipation	$T_C = 25^{\circ}C$	2100	W
RBSOA	Reverse Bias Safe Operating Area	$T_{j} = 125^{\circ}C$	800A @ 1100V	

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

#### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				750	μA
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.7	2.1	V
$V_{CE(sat)}$		$I_C = 400A$ $T_j =$	$T_j = 125$ °C		2.0		ľ
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 12mA$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V ; V_{CE} = 25V$ f = 1MHz			29		nF
$C_{res}$	Reverse Transfer Capacitance				1.3		111
$Q_{G}$	Gate charge	V <sub>GE</sub> =±15V, I <sub>C</sub> =400A V <sub>CE</sub> =600V			3.7		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			250		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			90		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_C = 400A$			550		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 1.8\Omega$		130			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (125°C)		300		
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 400A$ $R_{G} = 1.8\Omega$			100		ns
$T_{d(off)}$	Turn-off Delay Time				650		
$T_{\rm f}$	Fall Time				180		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		36		mJ
$E_{\text{off}}$	Turn off Energy	$I_C = 400A$ $R_G = 1.8\Omega$	$T_j = 125$ °C		62		1113
$I_{sc}$	Short Circuit data	$V_{GE} \le 15V$ ; $V_{Bus} = 900V$ $t_p \le 10 \mu s$ ; $T_i = 125 ^{\circ}C$			1600		A

Reverse diode ratings and characteristics

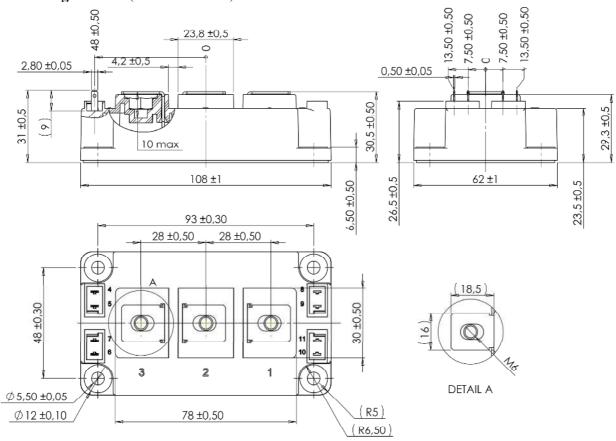
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1200			V
$I_{RRM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_i = 25$ °C $T_i = 125$ °C			750 1000	μΑ
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		400		A
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 400A$	$T_i = 25^{\circ}C$		1.6	2.1	V
V F	Diode Polward Voltage	$V_{GE} = 0V$	$T_j = 125$ °C		1.6		v
+	Reverse Recovery Time	-	$T_j = 25^{\circ}C$		170		ne
$t_{rr}$	Reverse Recovery Time		$T_j = 125$ °C		280		ns
0	Q <sub>rr</sub> Reverse Recovery Charge	$I_F = 400A$ $V_R = 600V$ $di/dt = 4000A/\mu s$	$T_j = 25^{\circ}C$		36		C
Qrr			$T_{i} = 125^{\circ}C$		72		μC
E <sub>rr</sub>	Reverse Recovery Energy	T	$T_j = 25$ °C		20		m I
			$T_{j} = 125^{\circ}C$		36		mJ



### Thermal and package characteristics

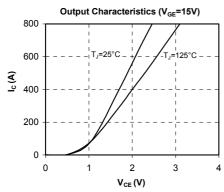
Symbol	Characteristic			Min	Тур	Max	Unit		
$R_{thJC}$	Junction to Case Thermal Resistance		IGBT			0.06	°C/W		
			Diode			0.13	C/ W		
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V		
$T_{J}$	Operating junction temperature range			-40		150			
$T_{STG}$	Storage Temperature Range	orage Temperature Range -40 12:				125	°C		
$T_{\rm C}$	Operating Case Temperature			-40		125			
Torque	Mounting torque	For terminals	M6	3		5	N.m		
		To Heatsink	M6	3		5	11.111		
Wt	Package Weight					350	g		

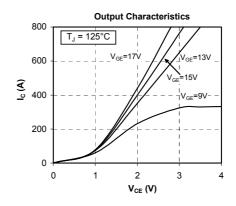
### D3 Package outline (dimensions in mm)

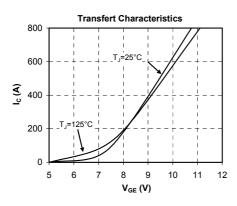


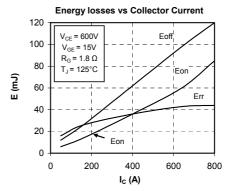


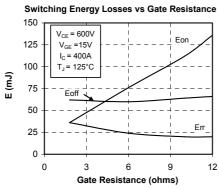
### **Typical Performance Curve**

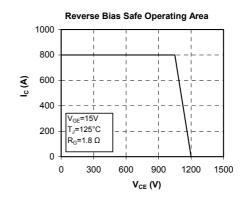


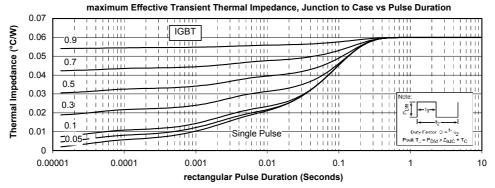




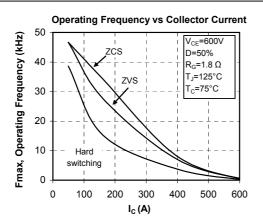


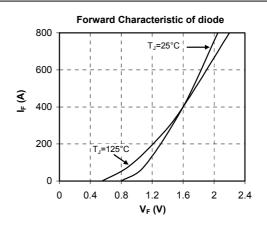


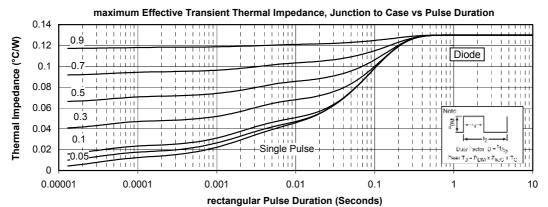














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